NSN 5962-01-089-9485

Memory Microcircuit - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5962-01-089-9485		
Body Length:		
0.760 inches		
Body Width:		
0.270 inches		
Body Height:		
0.150 inches		
Operating Tempurature Range:		
+0.0/+75.0 degrees celsius		
Storage Tempurature Range:		
-65.0/+150.0 degrees celsius		
Features Provided:		
Programmable and bipolar and high speed and w/open collector		
Inclosure Material:		
Ceramic		
Inclosure Configuration:		
Dual-in-line		
Output Logic Form:		
Transistor-transistor logic		
Input Circuit Pattern:		
10 input		
Terminal Surface Treatment:		
Solder		
Voltage Rating And Type Per Characteristic:		
7.0 volts power source		
Time Rating Per Chacteristic:		
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time	ne, high to low level	I
output		
Memory Device Type:		
Rom		
Terminal Type And Quantity:		
16 printed circuit		
Shelf Life:		
N/a		
Unit Of Measure:		
Demilitarization:		
Yes - demil/mli		
Fiig:		
A458a0		